

ACTIVE ISOLATED-INTEGRATOR LOW-PASS FILTER
WITH ATTENUATION POLES

RELATED APPLICATIONS

[0001] This application claims the benefit of United States Provisional Patent Application Serial Number 60/174,201, filed January 3, 2000, the complete disclosure of which is hereby expressly incorporated by reference.

BACKGROUND OF THE INVENTION

1. Field of the Invention.

[0002] The present invention relates to filters, and in particular to low-pass filters with attenuation poles.

2. Description of the Related Art.

[0003] While most of the literature on passive resistance-capacitance (RC) band-reject, frequency rejecting network (FRN), or notch filters has been dedicated to the bridged full-T filter, another passive RC filter overcomes some of the impracticalities of the bridged full-T filter. That filter is the isolated-integrator band-reject filter, as shown in Figure 1.

[0004] The isolated-integrator band-reject filter has several unique qualities, which the bridged full-T filter lacks. In terms of structure, the isolated-integrator band-reject filter uses capacitors of equal value. This enables the manufacturer to use capacitors of a single production batch, and to grade only one type of capacitor versus many types. Additionally, the capacitors used can be relatively inexpensive NPO ceramic types.

[0005] The net capacitance of the filter itself acts to aid the construction of a low-pass filter when incorporated into an active filter design. While attenuation with a voltage source

and an open circuit load is symmetrical, the natural design tendency is to include finite impedances for both the voltage source and the load. However, in practice it is more likely that the low-pass pass-band will be gain dominant.

[0006] Additionally, the frequency of the isolated-integrator band-reject filter may be tuned in both directions by trimming a single variable resistor. Beyond the advantage of use of a single member, the use of a resistor in particular permits laser trimming or abrasive adjustment methods, which can be applied to mass applied screened-on resistor types in the manufacturing processes. The use of a tuning resistor also enables the reduction of noise during the tuning process as the tuning resistor is connected to ground.

[0007] An additional feature of the filter is its ability to provide deep notches even at megahertz frequencies with practical values of components. The notches, or poles, remain deep, even when common component tolerance limits are incorporated. However, infinite notch depth may be attained only with exact and ideal values. Lastly, multiple isolated-integrator band-reject filters can be cascaded if necessary to produce multiple notches as part of the system response.

[0008] Additional information regarding resistance-capacitance notch filters is given in the paper "Tunable RC Null Networks," authored by Ralph Glasgal on pages 70-74 of the October 1969 issue of EEE which is expressly incorporated herein by reference.

SUMMARY OF THE INVENTION

[0009] The present invention involves the inclusion of an isolated-integrator band-reject filter into an active low-pass filter design. The isolated-integrator band-reject filter can be included in many different low-pass filters, such as Sallen & Key, multiple feedback, and

[0014] Figure 2(a) is a schematic view of second order low-pass Sallen & Key filter including an isolated-integrator band-reject filter in accordance with the present invention.

[0015] Figure 2(b) is a schematic view of a second order low-pass Sallen & Key filter including two isolated-integrator band-reject filters.

[0016] Figure 2(c) is a schematic view of a third order low-pass Sallen & Key filter including two isolated-integrator band-reject filters.

[0017] Figure 3 is a Bode diagram of the amplitude response of the filter of Figure 2(c).

[0018] Figure 4(a) is a schematic view of a multiple feedback low-pass filter including two imbedded isolated-integrator band-reject filters.

[0019] Figure 4(b) is a schematic view of a state-variable low-pass filter including two isolated-integrator band-reject filters.

[0020] Figure 5 is a schematic view of a pulse width modulated amplifier with a feedback filter in which the present invention could be utilized.

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DESCRIPTION OF THE PRESENT INVENTION

[0021] For the purposes of promoting an understanding of the principles of the invention, reference will now be made to the embodiments illustrated in the drawings and specific language will be used to describe the same. It will nevertheless be understood that no limitation of the scope of the invention is thereby intended. The invention includes any alterations and further modifications in the illustrated devices and described methods and further applications of the principles of the invention which would normally occur to one skilled in the art to which the invention relates.

[0023] Referring to Figure 1, a conventional isolated-integrator band-reject filter 20 is shown. The isolated-integrator band-reject filter 20 uses capacitors of equal value, designated C, which may be inexpensive NPO ceramic capacitors. In addition to using capacitors of equal value, the resistors R are of a single value. The exception to the general rule of equal value for resistors R is the single tuning resistor R/12, which is connected to ground and provides a means to prevent unwanted noise during the tuning process. As can be seen in Figure 1, resistor R/12 may be variable; however, the value shown is a value of R/12. In general, the ratio for the value of resistors R of isolated-integrator band-reject filter 20 to resistor R/12 is at worst 12 to 1, which is still well within the range of screened-on processes. Therefore, for simplification, the value presented is R/12.

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[0025] All three embodiments of the present invention shown in Figure 2 use amplifiers with positive gain, designated as K. The simplest possible implementation of the positive gain is to use a gain of unity, or one, since this eliminates the need for gain setting resistors on a voltage feedback operational amplifier. Gains larger than one, however, may result in simpler capacitor sizing and more stable circuit characteristics.

[0026] Turning now to the specific forms found in Figure 2, Figure 2(a) depicts the first embodiment of the present invention in which isolated-integrator band-reject filter 20 is incorporated into a Sallen & Key filter resulting in new filter 22. This is a second order system; however, only one finite frequency attenuation pole is produced. In comparison to the basic Sallen & Key filter, one should note that isolated-integrator band-reject filter 20 is used to replace portions of the original resistive branch. One should also note that resistors Rg, R5, and R8 and capacitors C3 and C5 are not part of isolated-integrator band-reject filter 20 and are not necessarily all of equal value.

[0027] During operation, one of resistors R5 or R8 could be zero in value; however, if both resistors had zero value, only a single pole at infinity would result. This single pole may be a workable result, although typically not the desired result. Resistor R7 is a variable resistor corresponding to resistor R/12 of Figure 1, and may have a large range of values, all of which are a fraction of resistors R6.

[0031] Figure 3 is the Bode diagram of the amplitude response in decibels (dB) of the third-order low-pass Sallen & Key filter 26 of Figure 2(c). This diagram depicts the attenuation resulting from the inclusion of isolated-integrator band-reject filters 20 in filter 26. One should note that the numbers used for the Bode diagram do not reflect the only operating parameter for the present invention, but one of many possibilities. The following component values produce the amplitude response depicted in Figure 3:

[0032] $K = 1$

[0033] $R_g = 2.71 \text{ K}\Omega$

[0034] $R_1 = R_4 = R_8 = 0 \Omega$

[0035] $R_2 = 1.24 \text{ K}\Omega$

[0036] $R_3 = 104 \Omega$

[0037] $R_5 = R_6 = 2.49 \text{ K}\Omega$

[0038] $R_7 = 208 \Omega$

[0039] $C_1 = C_2 = C_3 = C_4 = C_5 = 220 \text{ pf}$

[0040] It should be noted that R_1 is equal to R_4 , or both have a value of zero, thus there are only two poles occurring in the system, as stated in the description of the third-order system of Figure 2(c). The two poles of attenuation 32 and 34 occur at 500 KHz and 1 MHz, respectively. It is also notable that 500 KHz and 1 MHz are the locations where the ripple spectra is expected from a 250 KHz interleave $N = 2$ converter, or the location of harmonics resulting from a 250 KHz converter.

[0041] Another item to note is the amount of attenuation produced by the present invention. Specifically, one should note that over 70 dB of attenuation occurs at all frequencies above 450 KHz. Once the frequency reaches 100 KHz, the amplitude response experiences rapid attenuation going from 20 dB at 100 KHz to over 70 dB at 450 KHz. In comparison, the response is only attenuated by 20 dB from 1 KHz to 100 KHz.

[0042] Referring now to Figure 4, both multiple feedback and state variable type filters may be implemented with imbedded isolated-integrator band-reject filters 20 in the feed-forward resistive branches of each filter type. Using isolated-integrator band-reject filters 20 in these types of filters provides additional embodiments of the present invention.

[0043] Figure 4(a) shows a fourth embodiment of the present invention, or filter 28, by depicting a multiple-feedback filter having a pair of isolated-integrator band-reject filters 20 creating two poles, or notches, for the system. Depending on the order of the multiple-feedback filter, this embodiment of the present invention can be inverting at DC, thus altering its potential uses. However, the addition of an inverter should correct any problems with inversion according to principles well known in the art.

[0044] In Figure 4(b), a fifth embodiment of the present invention is shown in which a state-variable filter includes isolated-integrator band-reject filters 20 resulting in filter 30. State-variable filters can be readily configured with three feed-forward resistive branches, each of which would support a frequency-rejecting network. However, the embodiment of the present invention disclosed shows the more common state-variable filter as including two feed-forward resistive branches with an isolated-integrator band-reject filter 20 in each branch as shown in Figure 4(b). Resultant filter 30 creates a double notch as did the multiple feedback type filter. Again, like the multiple feedback type filters, the inversion issue can affect the uses of this filter; but the inclusion of an inverter should correct the inversion problem.

[0045] If a frequency rejecting network, such as an isolated-integrator band-reject filter, is placed in the feedback path around a high-gain amplifier, the result is a band-pass or frequency-emphasizing network (FEN). Such derivations are considered within the scope of this invention.

[0046] Referring now to Figure 5, a block diagram depicts another embodiment of the present invention in which isolated-integrator band-reject filter 20 is included as part of feedback demodulation filter 44. This embodiment addresses the issue of removing pulse width modulated (PWM) spectra from the feedback signals of a fixed-frequency switch-mode amplifier. In the removal of the PWM spectra from the feedback signals, a high-performance amplifier may need two attenuation poles, or notches. In Figure 5, power amplifier 40 includes PWM power stage 42 driven by an error amp and modulator stage 43 producing PWM ripple spectra, and feedback demodulation filter 44 to remove the PWM ripple spectra from the feedback signal prior to entry into filter 46. Feedback demodulation filter 44 includes at least one isolated-integrator band-reject filter 20. An output demodulation filter 47 is connected to the load 45.

[0047] While this invention has been described as having an exemplary design, the present invention may be further modified within the spirit and scope of this disclosure. This application is therefore intended to cover any variations, uses, or adaptations of the invention using its general principles. Further, this application is intended to cover such departures from the present disclosure as come within known or customary practice in the art to which this invention pertains.